

Yangyang Wang

List of Publications by Year in descending order

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57
papers

4,412
citations

109137

35
h-index

143772

57
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58
docs citations

58
times ranked

4254
citing authors

#	ARTICLE	IF	CITATIONS
1	Extending Channel Scaling Limit of p-MOSFETs Through Antimonene With Heavy Effective Mass and High Density of State. IEEE Transactions on Electron Devices, 2022, 69, 857-862.	1.6	17
2	Modulating tunneling width and energy window for high-on-current two-dimensional tunnel field-effect transistors. Nano Energy, 2021, 81, 105642.	8.2	20
3	Large-scale Multifunctional Carbon Nanotube Thin Film as Effective Mid-Infrared Radiation Modulator with Long-Term Stability. Advanced Optical Materials, 2021, 9, 2001216.	3.6	32
4	Soft-chemistry synthesis, solubility and interlayer spacing of carbon nano-onions. RSC Advances, 2021, 11, 6850-6858.	1.7	14
5	Thermal infrared and broadband microwave stealth glass windows based on multi-band optimization. Optics Express, 2021, 29, 13610.	1.7	21
6	Schottky barrier heights in two-dimensional field-effect transistors: from theory to experiment. Reports on Progress in Physics, 2021, 84, 056501.	8.1	97
7	Layer-Dependent Photoabsorption and Photovoltaic Effects in Two-Dimensional Bi_2O_3 X_2		

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19	Bilayer tellurene-metal interfaces. <i>Journal of Semiconductors</i> , 2019, 40, 062003.	2.0	9
20	Interfacial Properties of Monolayer Antimonene Devices. <i>Physical Review Applied</i> , 2019, 11, .	1.5	22
21	Flexible Mid-Infrared Radiation Modulator with Multilayer Graphene Thin Film by Ionic Liquid Gating. <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 13538-13544.	4.0	47
22	Gate-tunable interfacial properties of in-plane ML MX ₂ 1T ² H heterojunctions. <i>Journal of Materials Chemistry C</i> , 2018, 6, 5651-5661.	2.7	54
23	Three-layer phosphorene-metal interfaces. <i>Nano Research</i> , 2018, 11, 707-721.	5.8	72
24	Electrical contacts in monolayer blue phosphorene devices. <i>Nano Research</i> , 2018, 11, 1834-1849.	5.8	55
25	High-performance sub-10-nm monolayer black phosphorene tunneling transistors. <i>Nano Research</i> , 2018, 11, 2658-2668.	5.8	47
26	n-Type Ohmic contact and p-type Schottky contact of monolayer InSe transistors. <i>Physical Chemistry Chemical Physics</i> , 2018, 20, 24641-24651.	1.3	33
27	n- and p-type ohmic contacts at monolayer gallium nitride-metal interfaces. <i>Physical Chemistry Chemical Physics</i> , 2018, 20, 24239-24249.	1.3	13
28	Monolayer tellurene-metal contacts. <i>Journal of Materials Chemistry C</i> , 2018, 6, 6153-6163.	2.7	81
29	Simulations of Quantum Transport in Sub-5-nm Monolayer Phosphorene Transistors. <i>Physical Review Applied</i> , 2018, 10, .	1.5	144
30	Sub-5 nm Monolayer Arsenene and Antimonene Transistors. <i>ACS Applied Materials & Interfaces</i> , 2018, 10, 22363-22371.	4.0	77
31	Many-Body Effect and Device Performance Limit of Monolayer InSe. <i>ACS Applied Materials & Interfaces</i> , 2018, 10, 23344-23352.	4.0	98
32	Can a Black Phosphorus Schottky Barrier Transistor Be Good Enough?. <i>ACS Applied Materials & Interfaces</i> , 2017, 9, 3959-3966.	4.0	70
33	Many-body Effect, Carrier Mobility, and Device Performance of Hexagonal Arsenene and Antimonene. <i>Chemistry of Materials</i> , 2017, 29, 2191-2201.	3.2	244
34	Monolayer Bismuthene-Metal Contacts: A Theoretical Study. <i>ACS Applied Materials & Interfaces</i> , 2017, 9, 23128-23140.	4.0	73
35	A computational study of monolayer hexagonal WTe ₂ to metal interfaces. <i>Physica Status Solidi (B): Basic Research</i> , 2017, 254, 1600837.	0.7	17
36	Schottky Barriers in Bilayer Phosphorene Transistors. <i>ACS Applied Materials & Interfaces</i> , 2017, 9, 12694-12705.	4.0	94

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37	Black phosphorus transistors with van der Waals-type electrical contacts. <i>Nanoscale</i> , 2017, 9, 14047-14057.	2.8	76
38	Electrical Contacts in Monolayer Arsenene Devices. <i>ACS Applied Materials & Interfaces</i> , 2017, 9, 29273-29284.	4.0	76
39	Controlled release of recombinant human cementum protein 1 from electrospun multiphasic scaffold for cementum regeneration. <i>International Journal of Nanomedicine</i> , 2016, Volume 11, 3145-3158.	3.3	34
40	Does the Dirac cone of germanene exist on metal substrates?. <i>Physical Chemistry Chemical Physics</i> , 2016, 18, 19451-19456.	1.3	39
41	Rise of silicene: A competitive 2D material. <i>Progress in Materials Science</i> , 2016, 83, 24-151.	16.0	713
42	Interfacial properties of stanene-metal contacts. <i>2D Materials</i> , 2016, 3, 035020.	2.0	26
43	Performance Upper Limit of sub-10 nm Monolayer MoS ₂ Transistors. <i>Advanced Electronic Materials</i> , 2016, 2, 1600191.	2.6	97
44	Interfacial Properties of Monolayer and Bilayer MoS ₂ Contacts with Metals: Beyond the Energy Band Calculations. <i>Scientific Reports</i> , 2016, 6, 21786.	1.6	224
45	Interfacial Properties of Monolayer MoSe ₂ -Metal Contacts. <i>Journal of Physical Chemistry C</i> , 2016, 120, 13063-13070.	1.5	70
46	Monolayer Phosphorene-metal Contacts. <i>Chemistry of Materials</i> , 2016, 28, 2100-2109.	3.2	199
47	Does p-type ohmic contact exist in WSe ₂ -metal interfaces?. <i>Nanoscale</i> , 2016, 8, 1179-1191.	2.8	166
48	Graphdiyne-metal contacts and graphdiyne transistors. <i>Nanoscale</i> , 2015, 7, 2116-2127.	2.8	94
49	Silicene nanomesh. <i>Scientific Reports</i> , 2015, 5, 9075.	1.6	42
50	All-metallic Vertical Transistors Based on Stacked Dirac Materials. <i>Advanced Functional Materials</i> , 2015, 25, 68-77.	7.8	59
51	Strong band hybridization between silicene and Ag(111) substrate. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2014, 58, 38-42.	1.3	43
52	Does the Dirac Cone Exist in Silicene on Metal Substrates?. <i>Scientific Reports</i> , 2014, 4, 5476.	1.6	92
53	Interfacial Properties of Bilayer and Trilayer Graphene on Metal Substrates. <i>Scientific Reports</i> , 2013, 3, 2081.	1.6	86
54	Tunable band gap in few-layer graphene by surface adsorption. <i>Scientific Reports</i> , 2013, 3, .	1.6	55

#	ARTICLE	IF	CITATIONS
55	Enhanced many-body effects in one-dimensional linear atomic chains. Physica Status Solidi (B): Basic Research, 2013, 250, 1636-1643.	0.7	7
56	Tunable and sizable band gap in silicene by surface adsorption. Scientific Reports, 2012, 2, 853.	1.6	253
57	Tunable and sizable band gap in silicene by surface adsorption. , 0, .		1